

Multi-Protocol Wireless Module with PA



Key Features

- Microcontroller
 - Powerful 48-MHz Arm[®] Cortex[®]-M4F processor
 - > 352KB of in-system Programmable Flash
 - > 256KB of ROM for protocols and library functions
 - > 8KB of Cache SRAM (Alternatively available as general-purpose RAM)
 - 80KB of ultra-low leakage SRAM. The SRAM is protected by parity to ensure high reliability of operation.
 - > 2-Pin cJTAG and JTAG debuggingRF performance
 - Supports Over-the-Air upgrade (OTA)
- Ultra-low power sensor controller with 4KB of SRAM
 - Sample, store, and process sensor data
 - > Operation independent from system CPU
 - Fast wake-up for low-power operationBQB, FCC, CE, RoHS compliant
- TI-RTOS, drivers, Bootloader, Bluetooth[®] 5 Low Energy Controller, and IEEE 802.15.4 MAC in ROM for optimized application size
- Peripherals
 - > Digital peripherals can be routed to any GPIO
 - ➢ 4× 32-bit or 8× 16-bit general-purpose timers
 - > 12-Bit ADC, 200 kSamples/s, 8 channels
 - > 2× comparators with internal reference DAC
 - (1× continuous time, 1× ultra-low power)
 - Programmable current source
 - 2× UART
 - > 2× SSI (SPI, MICROWIRE, TI)
 - ► I2C
 - ► 12S
 - Real-Time Clock (RTC)
 - AES 128- and 256-bit Crypto Accelerator
 - > ECC and RSA Public Key Hardware Accelerator
 - SHA2 Accelerator (Full suite up to SHA-512)
 - True Random Number Generator (TRNG)





- Capacitive sensing, up to 8 channels
- Integrated temperature and battery monitor
- External system
 - On-chip Buck DC/DC converter
- Low power
 - Wide supply voltage range: 1.8 V to 3.8 V
 - Active-Mode RX: 6.9 mA
 - Active-Mode TX 0 dBm: 7.3 mA
 - Active-Mode TX 5 dBm: 9.6 mA
 - Active-Mode TX at +10 dBm: 22 mA
 - Active-Mode TX at +20 dBm: 85 mA
 - Active-Mode MCU 48 MHz (CoreMark):
 - > 3.4 mA (71 μA/MHz)
 - Sensor Controller, Low Power-Mode, 2 MHz, running infinite loop: 30.1 μA
 - Sensor Controller, Active-Mode, 24 MHz, running infinite loop: 808 μA
 - Standby: 0.94 μA (RTC on, 80KB RAM and CPU retention)
 - Shutdown: 150 nA (wakeup on external events)
- Radio section
 - 2.4 GHz RF transceiver compatible with Bluetooth 5 Low Energy and IEEE 802.15.4 PHY and MAC
 - Excellent receiver sensitivity:
 - 100 dBm for 802.15.4 (2.4 GHz),
 - –105 dBm for Bluetooth 125-kbps (LE Coded PHY)
 - Output power up to +20 dBm with temperature compensation
 - > Suitable for systems targeting compliance with worldwide radio frequency regulations
- Wireless protocols
 - `Thread, Zigbee[®], Bluetooth[®] 5 Low Energy, IEEE 802.15.4g, IPv6-enabled smart objects (6LoWPAN), Wi-SUN[®], proprietary systems, SimpleLink[™] TI 15.4-Stack (2.4 GHz), and Dynamic Multiprotocol Manager (DMM) driver.
- Size: 29.86 mm x 19.98 mm x 2.15 mm (With Shielding)
- FCC, CE Compliant

Descriptions

BDE-RFM207 is a multiprotocol 2.4G wireless module targeted at low power sensors and PC/Phone accessories. It supports Thread, Zigbee, Bluetooth 5 Low Energy, IEEE 802.15.4g, IPv6-enabled smart objects (6LoWPAN), Wi-SUN, proprietary systems, SimpleLink TI 15.4-Stack (2.4 GHz), and Dynamic Multiprotocol Manager (DMM) driver.

BDE-RFM207P has an integrated power amplifier, which enable 20 dBm output power.



BDE-RFM207 highly integrates radio, stack, profile and applications in a SoC, without the need of using an external MCU. The module also offers flexible hardware interfaces for the sensor application. It enables ultra-low power connectivity and data transfer for the applications that are sensitive to power consumption, size and cost.

Block Diagram



Fig. 1: The Block Diagram of BDE-RFM207P

Applications

- 2400 to 2480 MHz ISM and SRD systems with down to 4 kHz of receive bandwidth
- Building automation
- Grid infrastructure
- Industrial transport asset tracking
- Factory automation and control
- Medical
- Electronic point of sale (EPOS) Electronic Shelf Label (ESL)

Electrical Characteristics



Absolute maximum rating

Rating	Min	Тур	Max	Unit	Notes
Storage Temperature	-40	-	125	°C	
VDD	-0.3	-	4.1	V	
Other Digital Terminals	-0.3	-	VDDS+0.3≤4.1	V	
Voltage on ADC input	-0.3	-	VDDS	V	Voltage scaling enabled
	-0.3	-	1.49	V	Voltage scaling disabled, internal reference
	-0.3	-	VDDS/2.9	V	Voltage scaling disabled, VDDS as reference
RF pin	-	-	2	dBm	

Recommended operating conditions

Rating	Min	Тур	Max	Unit
Operating Temperature	-40	-	85	°C
VDD	2.1	3.3	3.8	V

Pinout

BDE-RFM207P







Pin Number	Pin Name	Definitions
1	GND	Power Ground
2	NC	NC
3	GND	Power Ground
4	GND	Power Ground
5	NC	NC
6	NC	NC
7	DIO_5	GPIO, High-drive Capability
8	DIO_6	GPIO, High-drive Capability
9	DIO_7	GPIO, High-drive Capability
10	DIO_8	GPIO
11	DIO_9	GPIO
12	DIO_10	GPIO
13	GND	Power Ground
14	VDD	Supply Power
15	VDD	Supply Power
16	DIO_11	GPIO
17	DIO_12	GPIO
18	DIO_13	GPIO
19	DIO_14	GPIO
20	DIO_15	GPIO
21	JTAG_TMSC	JTAG TMSC, High-drive Capability
22	JTAG_TCKC	JTAG TCKC
23	DIO_16	GPIO, JTAG_TDO, High-drive Capability
24	DIO_17	GPIO, JTAG_TDI, High-drive Capability
25	DIO_18	GPIO
26	DIO_19	GPIO

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BDE-RFM207P

27	DIO_20	GPIO	
28	DIO_21	GPIO	
29	DIO_22	GPIO	
30	RESET	Reset, Active Low	
31	DIO_23	GPIO, Analog Capability	
32	DIO_24	GPIO, Analog Capability	
33	DIO_25	GPIO, Analog Capability	
34	DIO_26	GPIO, Analog Capability	
35	DIO_27	GPIO, Analog Capability	
36	DIO_28	GPIO, Analog Capability	
37	NC	NC	
38	NC	NC	
39	GND	Power Ground	
40	GND	Power Ground	
41	RFOUT	2.4G RF Output Port	
42	GND	Power Ground	

Overall Dimensions

Fig. 3 shows the overall dimensions of BDE-RFM207P. The module measures 29.86mm long by 19.97mm wide by 2.15mm high with the shield.



Fig. 3: Overall Dimensions of BDE-RFM207P

Module Location



In order to get a fine performance when integrate the module to your product, it is advised to use the recommended module location to the respective PCB.

■ Location in X-Y plane





Fig. 4: Recommended location in X-Y plane



Fig. 5: Not recommended location in X-Y plane

Location in Z plane





Fig. 6: Recommended location in Z plane



Fig. 7: Not recommended location in Z plane

Typical Solder Reflow Profile



Fig. 8: Typical Solder Reflow Profile

Package Information



BDE-RFM207P



Fig. 9: Package

Contacts

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